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11-21-06  
Date \_\_\_\_\_  
Jennifer A. Steele

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants : Timothy B. Cowles, Michael A. Shore and Patrick J. Mullarkey  
Attorney Docket No.: 500792.05  
Patent No. : US 6,850,457 B2  
Serial No. : 10/043,682  
Issue Date : February 1, 2005  
Filed : January 10, 2002  
Title : REFRESH CONTROLLER AND ADDRESS REMAPPING CIRCUIT AND METHOD FOR DUAL MODE FULL/REDUCED DENSITY DRAMS

**REQUEST FOR CERTIFICATE OF CORRECTION**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**Certificate**  
NOV 30 2006  
**of Correction**

Sir:

A Certificate of Correction under 35 U.S.C. § 254 is respectfully requested for the above-identified patent in order to correct Patent and Trademark Office errors made during the printing of the patent. The changes in the patent needed to correct the errors are as follows:

<u>Column, Line</u>	<u>Reads</u>	<u>Should Read</u>
Item (75), Line 1	"Timoty B. Cowles,"	--Timothy B. Cowles,--
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Column 1, Line 38	"memory cell in an"	--memory cell in--
Column 1, Line 46	"or decreased"	--or decrease--

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Column 1, Line 56	"in the art. DRAM memory"	--in the art, DRAM memory--
Column 2, Line 2	"logic level of can no longer"	--logic level can no longer--
Column 2, Line 5	"example, as a result"	--example, a result--
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Column 2, Line 21	"complimentary"	--complementary--
Column 2, Line 24	"to store in"	--to store--
Column 2, Lines 65 and 67	"DRAM's"	--DRAMs--
Column 3, Line 10	"command are applied"	--commands are applied--
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Column 5, Line 37	"then energized"	--then energizes--
Column 6, Line 35	"DO"	--D0--
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Column 7, Lines 3 and 7-8	"complimentary"	--complementary--
Column 7, Line 5	"DO and its compliment DO*"	--D0 and its complement D0*--
Column 7, Lines 22 and 24	"VT"	--V <sub>T</sub> --
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Column 7, Line 39	“only one digit lines”	--only one digit line--
Column 7, Lines 57-58	“each Memory Address”	--each memory address--
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The Commissioner is hereby authorized to charge payment of any fees associated with this communication to Deposit Account No. 50-1266. A duplicate copy of this sheet is enclosed.

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Favorable consideration of this Request is respectfully requested.

Respectfully submitted,

Date: Nov. 20, 2006

By:



Edward W. Bulchis, Reg. No. 26,847

Customer No. 27,076

Dorsey & Whitney LLP

1420 Fifth Avenue, Suite 3400

Seattle, WA 98101

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Attorney for Applicant(s)

EWB:tdp

Enclosures:

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Form PTO-1050 (+ copy)

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DATED : February 1, 2005  
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MAILING ADDRESS OF SENDER:

**DORSEY & WHITNEY LLP**  
**1420 Fifth Avenue, Suite 3400**  
**Seattle, Washington 98101**

**FORM PTO-1050 (REV. 3-82)**

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Patent No. US 6,850,457 B2

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